

30 V, single P-channel Trench MOSFET 10 September 2012

Product data sheet

1. Product profile

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1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Trench MOSFET technology
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Tin-plated 100 % solderable side pads for optical solder inspection

1.3 Applications

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- Charging switch for portable devices
- DC-to-DC converters
- Power management in battery-driven portable devices
- Hard disk and computing power management

1.4 Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-30	V
V _{GS}	gate-source voltage	_		-20	-	20	V
I _D	drain current	V_{GS} = -10 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-6.8	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = -10 V; I _D = -4.7 A; T _j = 25 °C		-	40	50	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G
4	S	source		S 017aaa257
5	D	drain	Transparent top view	
6	D	drain	DFN2020MD-6 (SOT1220)	
7	D	drain		
8	S	source		

3. Ordering information

Table 3. Ordering information					
Type number Package					
	Name	Description	Version		
PMPB48EP	DFN2020MD-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220		

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB48EP	1U

5. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V_{GS} = -10 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-6.8	А
		V _{GS} = -10 V; T _{amb} = 25 °C	[1]	-	-4.7	А
		V _{GS} = -10 V; T _{amb} = 100 °C	[1]	-	-3	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-19	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	1.7	W
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Symbol	Parameter	Conditions		Min	Max	Unit
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.5	W
		T _{sp} = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode	'	1			
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.8	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

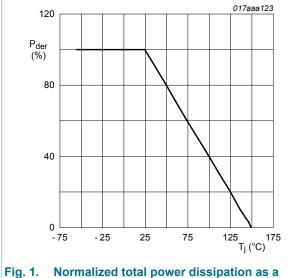


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

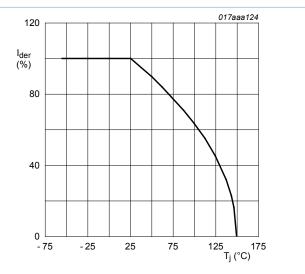
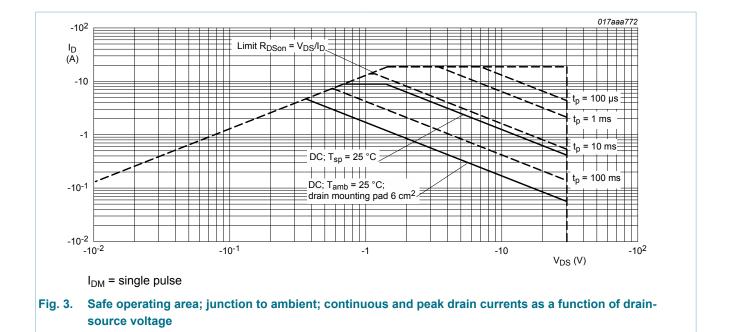


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ C)}} \times 100 \%$$

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6. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	-	[1]	-	235	270	K/W	
		[2]	-	67	74	K/W	
	ampient	in free air; t ≤ 5 s	[2]	-	33	36	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

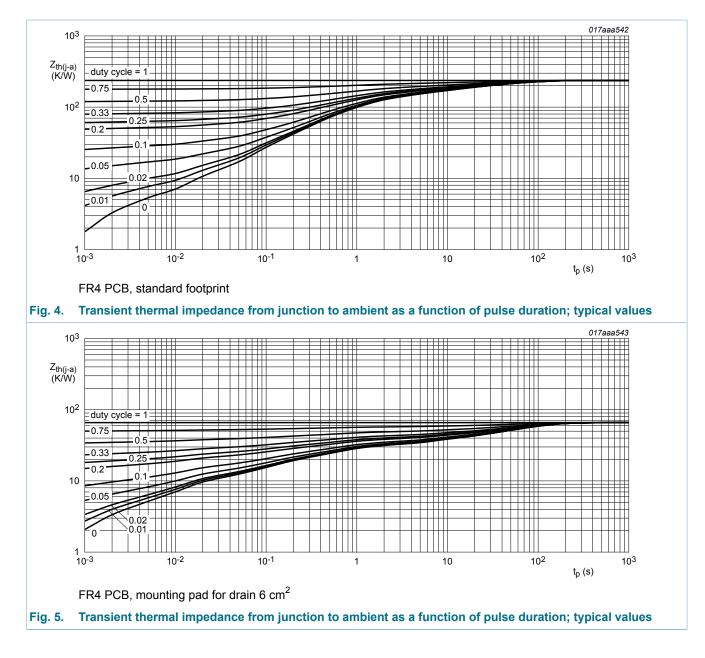
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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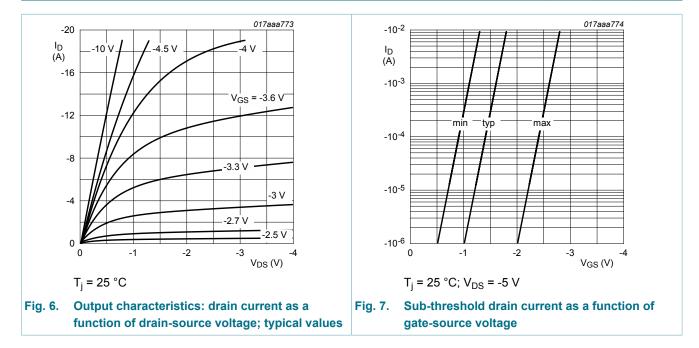
7. Characteristics

Table 7. C	haracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C		-30	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C		-1	-1.5	-2.5	V
I _{DSS}	drain leakage current	V_{DS} = -30 V; V_{GS} = 0 V; T_j = 25 °C		-	-	-1	μA
I _{GSS}	gate leakage current	V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C		-	-	-100	nA
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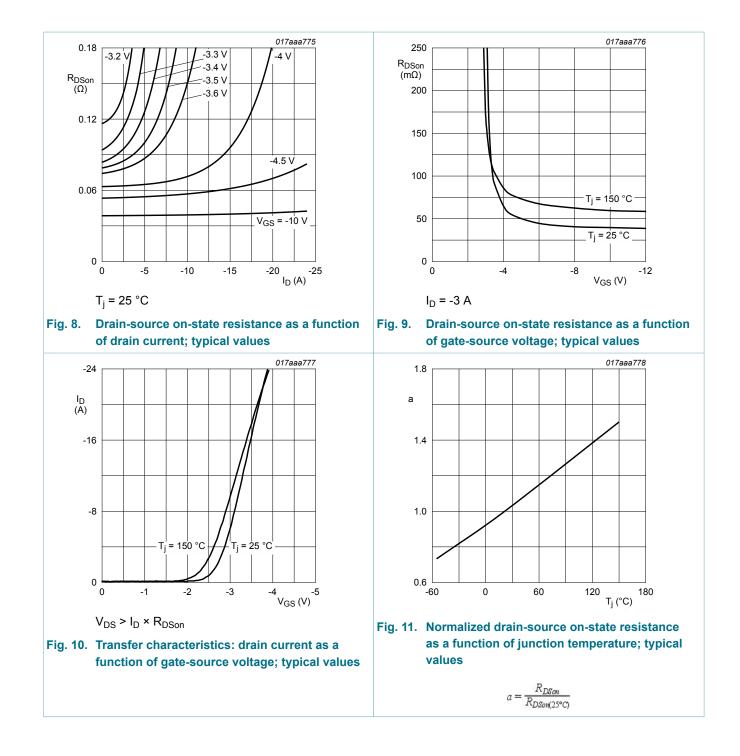
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V_{GS} = -10 V; I _D = -4.7 A; T _j = 25 °C	-	40	50	mΩ
	resistance	V _{GS} = -10 V; I _D = -4.7 A; T _j = 150 °C	-	60	75	mΩ
		V_{GS} = -4.5 V; I _D = -3.9 A; T _j = 25 °C	-	55	76	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -4.7 A; T _j = 25 °C	-	15	-	S
R _G	gate resistance	f = 1 MHz	-	6	-	Ω
Dynamic c	haracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = -15 V; I _D = -4.7 A; V _{GS} = -10 V;	-	17	26	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.5	-	nC
Q _{GD}	gate-drain charge	_	-	3.2	-	nC
C _{iss}	input capacitance	V _{DS} = -15 V; f = 1 MHz; V _{GS} = 0 V;	-	860	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	105	-	pF
C _{rss}	reverse transfer capacitance		-	87	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -15 V; I _D = -4.7 A; V _{GS} = -10 V;	-	7.4	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	17.5	-	ns
t _{d(off)}	turn-off delay time		-	27	-	ns
t _f	fall time	-	-	10.4	-	ns
Source-dra	in diode					
V _{SD}	source-drain voltage	I_{S} = -1.8 A; V_{GS} = 0 V; T_{j} = 25 °C	-	-0.8	-1.2	V



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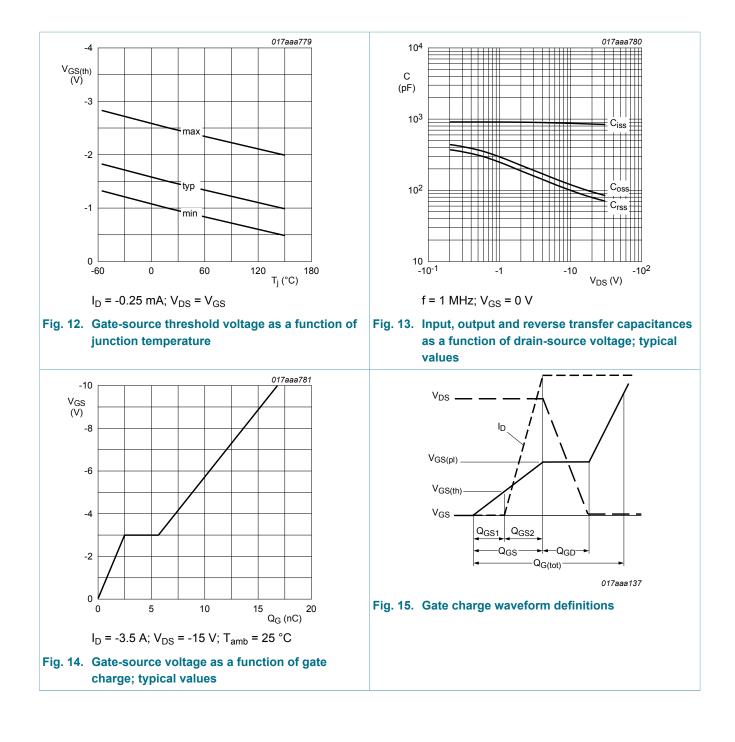
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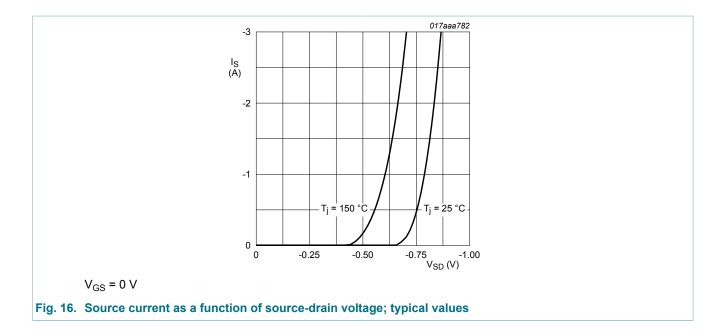
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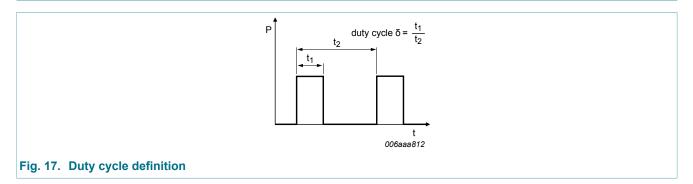


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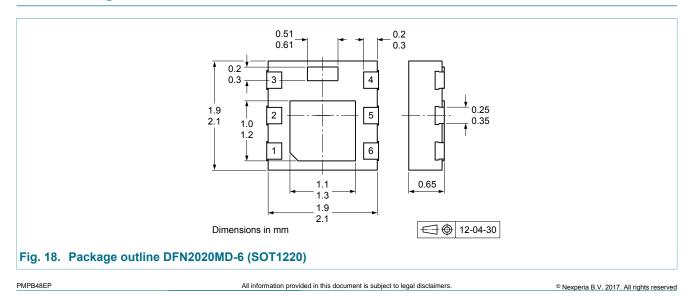
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8. Test information

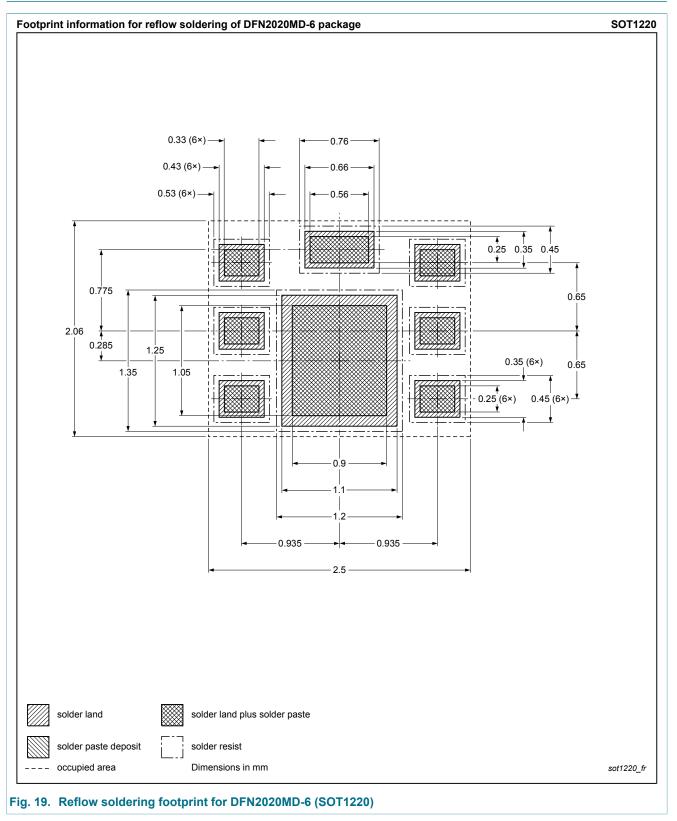


9. Package outline



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10. Soldering



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11. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PMPB48EP v.1	20120910	Product data sheet	-	-	

30 V, single P-channel Trench MOSFET

12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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30 V, single P-channel Trench MOSFET

13. Contents

1	Product profile1
1.1	General description1
1.2	Features and benefits1
1.3	Applications1
1.4	Quick reference data1
2	Pinning information2
3	Ordering information2
4	Marking2
5	Limiting values2
6	Thermal characteristics4
7	Characteristics5
8	Test information9
9	Package outline9
10	Soldering 10
11	Revision history11
12	Legal information12
12.1	Data sheet status 12
12.2	Definitions12
12.3	Disclaimers12
12.4	Trademarks13

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